

DOCKET NO.: 241014US2S DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
KOICHI KOKUBUN : ATTN: APPLICATION DIVISION
SERIAL NO: NEW APPLICATION :
FILED: HEREWITH :
FOR: SEMICONDUCTOR DEVICE :
HAVING TRENCH CAPACITOR :
FORMED IN SOI SUBSTRATE, :
AND METHOD OF :
MANUFACTURING THE SAME :

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to an examination on the merits, please amend the above-identified patent application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 5 of this paper.

Remarks begin on page 9 of this paper.